

View Online at <https://aerobasegroup.com/nsn/5961-01-356-4294>

Inclosure Material:

Metal all semiconductor device diode and ceramic all semiconductor device diode

Overall Length:

0.390 inches all semiconductor device diode

Overall Diameter:

0.104 inches all semiconductor device diode

Component Function Relationship:

Matched

Component Name And Quantity:

6 semiconductor device diode

Mounting Method:

Press fit all semiconductor device diode

Field Force Effect Type:

Electrostatic charge

Features Provided:

Burn in and electrostatic sensitive and hermetically sealed case

Semiconductor Material:

Silicon all semiconductor device diode

Voltage Rating In Volts Per Characteristic:

35.0 breakdown voltage, dc all semiconductor device diode

Capacitance Rating In Picofarads:

3.4 all semiconductor device diode and 3.8 all semiconductor device diode

Maximum Operating Temperature Per Measurement Point:

150.0 degrees celsius junction all semiconductor device diode

Terminal Type And Quantity:

2 ferrule all semiconductor device diode

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

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